#### **BS170**

# Small Signal MOSFET 500 mA, 60 Volts

**N-Channel TO-92 (TO-226)** 

#### **Features**

• This is a Pb-Free Device\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	Vdc
Gate-Source Voltage - Continuous - Non-repetitive (t <sub>p</sub> ≤ 50 μs)	V <sub>GS</sub> V <sub>GSM</sub>	±20 ±40	Vdc Vpk
Drain Current (Note)	I <sub>D</sub>	0.5	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C	P <sub>D</sub>	350	mW
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

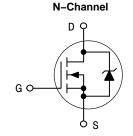
NOTE: The Power Dissipation of the package may result in a lower continuous drain current.



#### ON Semiconductor®

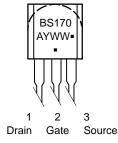
www.onsemi.com

## 500 mA, 60 Volts $R_{DS(on)} = 5.0 \Omega$





### MARKING DIAGRAM & PIN ASSIGNMENT



A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **BS170**

#### $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Gate Reverse Current $(V_{GS} = 15 \text{ Vdc}, V_{DS} = 0)$	I <sub>GSS</sub>	-	0.01	10	nAdc
Drain-Source Breakdown Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 100 μAdc)	V <sub>(BR)DSS</sub>	60	90	-	Vdc
ON CHARACTERISTICS (Note 1)				•	
Gate Threshold Voltage (V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mAdc)	V <sub>GS(Th)</sub>	0.8	2.0	3.0	Vdc
Static Drain–Source On Resistance (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 200 mAdc)	r <sub>DS(on)</sub>	-	1.8	5.0	Ω
Drain Cutoff Current (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0 Vdc)	I <sub>D(off)</sub>	-	_	0.5	μΑ
Forward Transconductance (V <sub>DS</sub> = 10 Vdc, I <sub>D</sub> = 250 mAdc)	9fs	-	200	-	mmhos
SMALL-SIGNAL CHARACTERISTICS					
Input Capacitance (V <sub>DS</sub> = 10 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	-	_	60	pF
SWITCHING CHARACTERISTICS					
Turn-On Time (I <sub>D</sub> = 0.2 Adc) See Figure 1	t <sub>on</sub>	-	4.0	10	ns
Turn-Off Time (I <sub>D</sub> = 0.2 Adc) See Figure 1	t <sub>off</sub>	-	4.0	10	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BS170	TO-92 (TO-226) (Pb-Free)	1000 Unit/Tube
BS170RLRAG	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

#### **RESISTIVE SWITCHING**

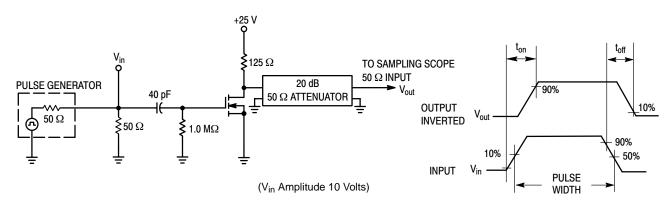


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

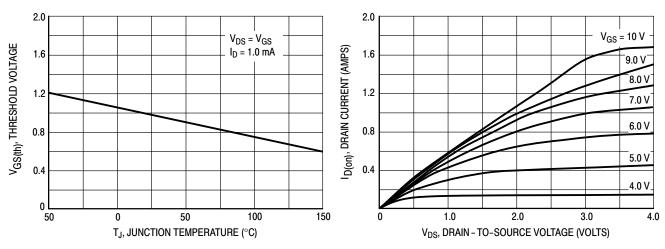


Figure 3. V<sub>GS(th)</sub> Normalized versus Temperature

Figure 4. On–Region Characteristics

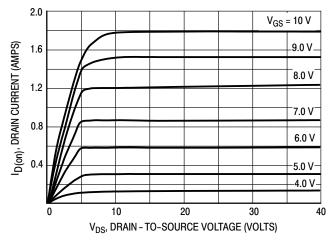


Figure 5. Output Characteristics

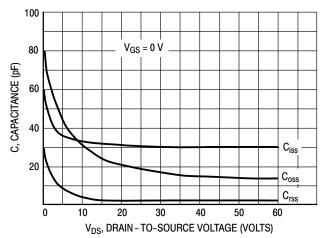
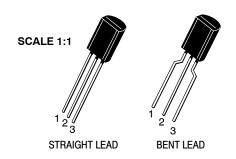
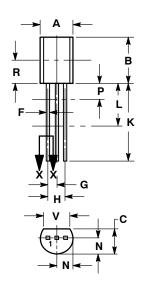


Figure 6. Capacitance versus Drain-To-Source Voltage



TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE A** 

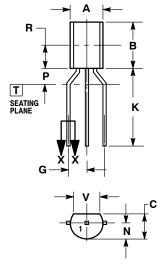
**DATE 08 MAY 2012** 



STRAIGHT LEAD



# **SECTION X-X**



**BENT LEAD** 



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1994.
  CONTROLLING DIMENSION: INCHES.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS
  UNCONTROLLED.
- UNIONI HOLLEU, DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME CONTROLLING DIMENSION: INCHES.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS
- UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

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D	0.018	0.021	0.46	0.53	
G	0.094	0.094 0.102 2.4		2.80	
J	0.018	0.024	0.46	0.61	
K	0.500		12.70		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.135		3.43		
V	0.135		3.43		

#### **STYLES ON PAGE 2**

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## **TO-92 (TO-226) 1 WATT** CASE 29-10

ISSUE A

#### DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN SOURCE GATE
	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2	STYLE 10: PIN 1. 2. 3.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	STYLE 13: PIN 1. 2. 3.	ANODE 1 GATE CATHODE 2	STYLE 14: PIN 1. 2. 3.	EMITTER COLLECTOR BASE	STYLE 15: PIN 1. 2. 3.	ANODE 1 CATHODE ANODE 2
PIN 1. 2.	ANODE	PIN 1.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
PINI 1	COLLECTOR EMITTER BASE	PIN 1.	SOURCE	PIN 1.	GATE	PIN 1. 2.	EMITTER	PIN 1. 2.	MT 1
	V <sub>CC</sub> GROUND 2 OUTPUT	STYLE 27: PIN 1. 2. 3.	MT SUBSTRATE MT	2.	CATHODE ANODE GATE	2.	NOT CONNECTED ANODE CATHODE	2.	DRAIN GATE SOURCE
PIN 1. 2.	GATE DRAIN SOURCE	PIN 1.	BASE	PIN 1. 2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

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